74HC2G34-Q100; 74HCT2G34-Q100

Dual buffer gate

Rev. 2 — 4 November 2013

Product data sheet

nexperia

1. General description

The 74HC2G34-Q100; 74HCT2G34-Q100 is a dual buffer. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Input levels:
 - For 74HC2G34-Q100: CMOS level
 - For 74HCT2G34-Q100: TTL level
- Wide supply voltage range from 2.0 V to 6.0 V
- Complies with JEDEC standard no. 7A
- High noise immunity
- ESD protection:
 - ◆ MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Low power dissipation
- Balanced propagation delays
- Unlimited input rise and fall times

3. Ordering information

Table 1. Ordering information

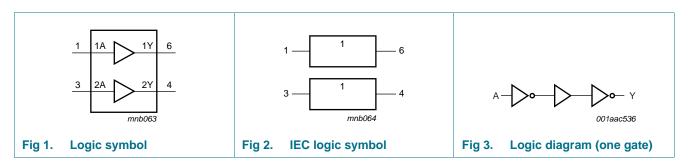
Type number	Package	ackage						
	Temperature range	Name	Description	Version				
74HC2G34GW-Q100	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363				
74HCT2G34GW-Q100								
74HC2G34GV-Q100	–40 °C to +125 °C	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457				
74HCT2G34GV-Q100								

4. Marking

Table 2. Marking	
Type number	Marking code ^[1]
74HC2G34GW-Q100	PA
74HCT2G34GW-Q100	UA
74HC2G34GV-Q100	P34
74HCT2G34GV-Q100	U34

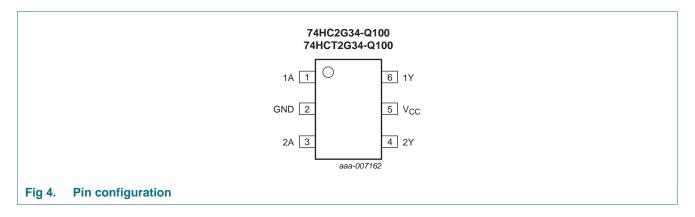
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
1A	1	data input
GND	2	ground (0 V)
2A	3	data input
2Y	4	data output
V _{CC}	5	supply voltage
1Y	6	data output

7. Functional description

Table 4. Function table^[1]

Input	Output
nA	nY
L	L
Н	Н

[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V_{l} < -0.5 V or V_{l} > V_{CC} + 0.5 V	<u>[1]</u> _	±20	mA
I _{OK}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
lo	output current	$V_{\rm O}$ = -0.5 V to V_{\rm CC} + 0.5 V	<u>[1]</u> _	±25	mA
I _{CC}	supply current		<u>[1]</u> _	+50	mA
I _{GND}	ground current		<u>[1]</u> _	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation		[2] _	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 and SC-74 packages: above 87.5 $^\circ$ C the value of P_{tot} derates linearly with 4.0 mW/K.

9. Recommended operating conditions

Table 6.	Recommended operating con	ditions				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Type 74HC	2G34-Q100					
V _{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
t _r	rise time	except for Schmitt trigger inputs				
		$V_{CC} = 2.0 V$	-	-	1000	ns
		$V_{CC} = 4.5 V$	-	-	500	ns
		$V_{CC} = 6.0 V$	-	-	400	ns
t _f	fall time	except for Schmitt trigger inputs				
		$V_{CC} = 2.0 V$	-	-	1000	ns
		$V_{CC} = 4.5 V$	-	-	500	ns
		$V_{CC} = 6.0 V$	-	-	400	ns
Type 74HC	T2G34-Q100					
V _{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
t _r	rise time	except for Schmitt trigger inputs				
		$V_{CC} = 4.5 V$	-	-	500	ns
t _f	fall time	except for Schmitt trigger inputs				
		$V_{CC} = 4.5 V$	-	-	500	ns

10. Static characteristics

Table 7. Static characteristics for 74HC2G34-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	1.2	-	V
		$V_{CC} = 4.5 V$	3.15	2.4	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 2.0 V$	-	0.8	0.5	V
		$V_{CC} = 4.5 V$	-	2.1	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	V

Table 7. Static characteristics for 74HC2G34-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Uni
V _{он}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	2.0	-	V
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.18	4.32	-	V
		$I_0 = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.68	5.81	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
1	input leakage current	$V_{I} = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μA
lcc	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$	-	-	1.0	μA
		$V_{CC} = 6.0 V$				
CI	input capacitance		-	1.5	-	pF
T _{amb} = -40	°C to +85 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	-	-	V
		$V_{CC} = 4.5 V$	3.15	-	-	V
		$V_{CC} = 6.0 V$	4.2	-	-	V
VIL	LOW-level input voltage	$V_{CC} = 2.0 V$	-	-	0.5	V
		$V_{CC} = 4.5 V$	-	-	1.35	V
		$V_{CC} = 6.0 V$	-	-	1.8	V
/IL	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
і Сс Гать = -40 /ін /іц /оц		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.13	-	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.63	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	-	0.33	V
		$I_0 = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
₁	input leakage current	$V_{I} = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$			10.0	μA

Table 7. Static characteristics for 74HC2G34-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -40	°C to +125 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	-	-	V
		$V_{CC} = 4.5 V$	3.15	-	-	V
		$V_{CC} = 6.0 V$	4.2	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 2.0 V$	-	-	0.5	V
		$V_{CC} = 4.5 V$	-	-	1.35	V
		$V_{CC} = 6.0 V$	-	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_O = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_O = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		I_O = -4.0 mA; V_{CC} = 4.5 V	3.7	-	-	V
		I_{O} = -5.2 mA; V_{CC} = 6.0 V	5.2	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
l _i	input leakage current	$V_{I} = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 6.0 \text{ V}$	-	-	20.0	μA

Table 8. Static characteristics for 74HCT2G34-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 25 °	3 °					
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	-	V
		$I_O = -4.0$ mA; $V_{CC} = 4.5$ V	4.18	4.32	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	V
l _l	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 5.5 \text{ V}$	-	-	1.0	μΑ
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 2.1 \text{ V};$ $V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}; I_{O} = 0 \text{ A}$	-	-	300	μΑ
CI	input capacitance		-	1.5	-	pF

Table 8. Static characteristics for 74HCT2G34-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -40) °C to +85 °C					
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.13	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	-	0.33	V
l _l	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 5.5 \text{ V}$			10.0	μA
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 2.1 \text{ V};$ $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_{O} = 0 \text{ A}$	-	-	375	μA
T _{amb} = -40) °C to +125 °C					
VIH	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	V
VIL	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	-	-	V
		$I_O = -4.0$ mA; $V_{CC} = 4.5$ V	3.7	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	-	0.4	V
I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μΑ
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 5.5 \ V \end{array}$	-	-	20.0	μΑ
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 2.1 V;$ $V_{CC} = 4.5 V$ to 5.5 V; $I_{O} = 0 A$	-	-	410	μA

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +1	25 °C	Unit
			_		Тур	Max	Min	Max (85 °C)	Max (125 °C)	-
74HC2G3	4-Q100									
t _{pd}	propagation delay	nA to nY; see Figure 5	[1]							
		$V_{CC} = 2.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	29	75	-	95	125	ns
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	9	15	-	19	25	ns
		$V_{CC} = 6.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	8	13	-	16	20	ns
t _t	transition time	nY; see <u>Figure 5</u>	[2]							
		$V_{CC} = 2.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	18	75	-	95	125	ns
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	6	15	-	19	25	ns
		$V_{CC} = 6.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	5	13	-	16	20	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC}	<u>[3]</u>	-	10	-	-	-	-	pF
74HCT2G	34-Q100									
t _{pd}	propagation delay	nA to nY; see Figure 5	[1]							
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	10	18	-	23	29	ns
t _t	transition time	nY; see <u>Figure 5</u>	[2]							
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	6	15	-	19	25	ns
C _{PD}	power dissipation capacitance	V_{I} = GND to V_{CC} – 1.5 V	[3]	-	9	-	-	-	-	pF

[1] t_{pd} is the same as t_{PLH} and t_{PHL}

[2] t_t is the same as t_{TLH} and t_{THL}

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma(C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12. Waveforms

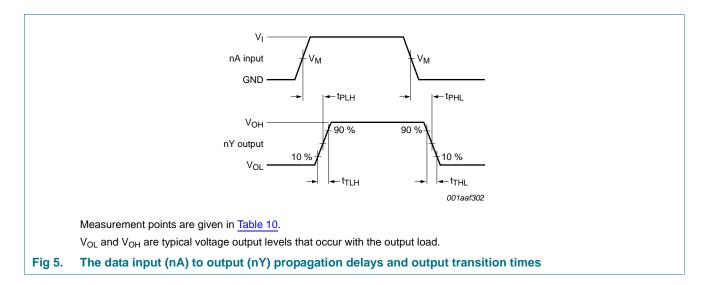


Table 10. Measurement points

Туре	Input Output			Output
	V _M	VI	t _r = t _f	V _M
74HC2G34-Q100	0.5V _{CC}	GND to V _{CC}	6.0 ns	0.5V _{CC}
74HCT2G34-Q100	1.3 V	GND to 3.0 V	6.0 ns	1.3 V

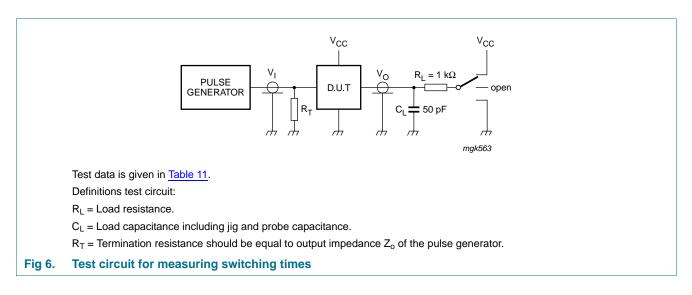
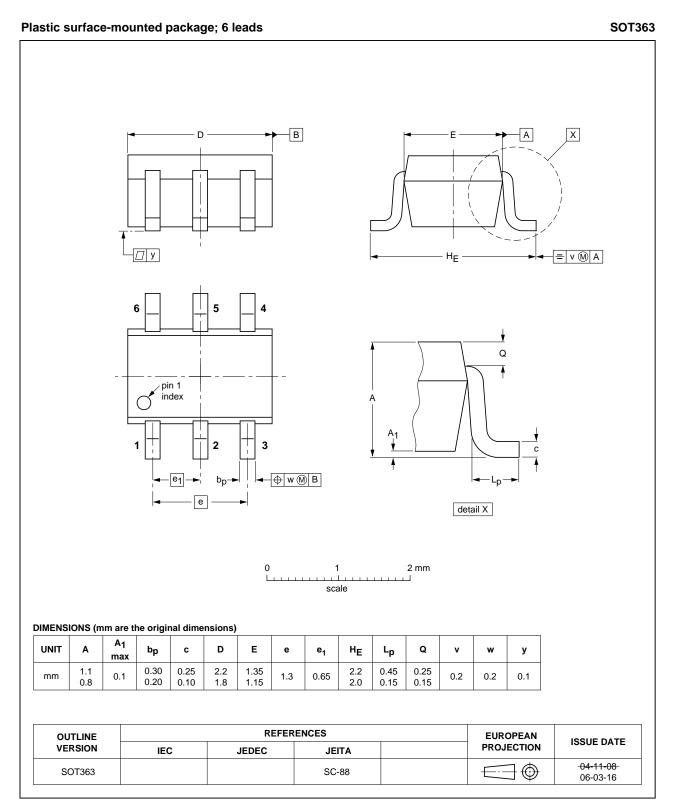


Table 11. Test data

Туре	Input	Input	
	VI	t _r , t _f	t _{PHL} , t _{PLH}
74HC2G34-Q100	GND to V _{CC}	6 ns	open
74HCT2G34-Q100	GND to 3.0 V	6 ns	open

13. Package outline



74HC_HCT2G34_Q100

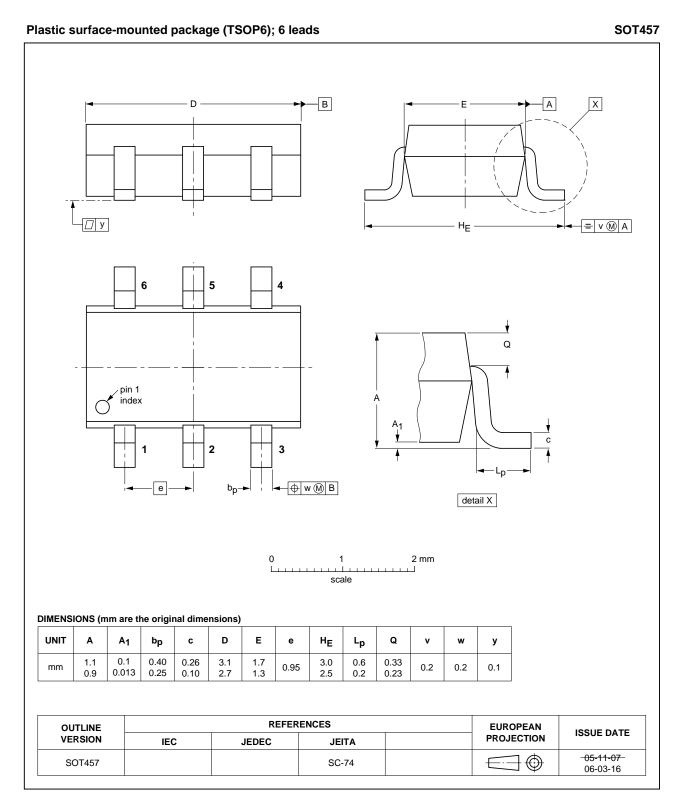


Fig 8. Package outline SOT457 (SC-74)

74HC_HCT2G34_Q100

14. Abbreviations

Table 12. Abbreviations		
Acronym	Description	
CMOS	Complementary Metal Oxide Semiconductor	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
MIL	Military	
MM	Machine Model	
DUT	Device Under Test	

15. Revision history

Table 13.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT2G34_Q100 v.2	20131104	Product data sheet	-	74HC_HCT2G34_Q100 v.1
Modifications:	 Added type num 	ber 74HC2G34GW ar	nd 74HCT2G34GW	/ (SOT363)
74HC_HCT2G34_Q100 v.1	20130417	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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For more information, please visit: <u>http://www.nexperia.com</u>

For sales office addresses, please send an email to: salesaddresses@nexperia.com

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